

Failure Analysis of Module-Integrated Electronics

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Develop techniques and perform failure analysis for improved quality, reliability, and safety of integrated electronics. Lifetimes of electronics should match with the modules into which they are integrated.

Why study electronics?

- 37% of unscheduled maintenance events and 59% of unscheduled maintenance costs are due to the inverter (largest category).
- 51% of PV system failures due to the central inverter.
- Inverter is largest PV system failure category (43%) and responsible for most kWh lost (36%).

L. M. Moore and H. N. Post, "Five years of operating experience at a large, utilityscale photovoltaic generating plant," Progress in Photovoltaics: Research and Applications 16(3): 249-259, 2008 "Reliability of Power Electronic Systems", Industrial Seminar, F. Blaabjerg, F. lannuzzo, K. Ma, IEEE APEC 2016, March 2016.

"Owner/Operator Perspective on Reliability Customer Needs and Field Data", Sandia National Laboratories, Utility-Scale Grid-Tied PV Inverter Reliability Workshop, January 2011.

A. Golnas, "PV System Reliability: An Operator's Perspective," IEEE Journal of Photovoltaics, **3**, pp.416-421, Jan. 2013.

Goal:

Types of electronics:

- Central inverters
- Micro-inverters
- Distributed inverters with power optimizers
- Bypass diodes

Types of stresses:

- Moisture
- Temperature and thermal cycles
- High voltage and/or current
- Chemical contamination
- Electromagnetic interference
- Mechanical tension/torque/vibration
- Ultraviolet radiation

Types of failures:

- Corrosion
- Solder joint fatigue
- Plated through-hole fatigue
- Conductive anodic filament formation
- Tin whisker formation
- Shock or vibration
- Potting induced (mechanical or corrosion)
- Flame retardant induced corrosion
- Solder flux adhesion and/or corrosion
- Component wear out

Areas of study:

- Device deconstruction
- Failure analysis methodologies
- Materials interaction/corrosion
- Adhesion
- Moisture ingress
- Thermal modeling
- Design for reliability

			Characterizat	ion tools to use:			Scanning Can	acitance Microscony	
	Thermal Imaging and Lock-In Thermography				Atomic Force Microscope (AFM) – based techniques		 Scanning Supachance Microscopy Scanning Spreading Resistance Microscopy (SSRM) Scanning Kelvin Probe Force 		
	Amplitude lock-in image	Phase lock-in image	X-Ray Tomography	Scanning Electron Microscope (SEM)	(a)) AFM	Microscopy (S (b) SKPFM potential	KPFM) (c) Electric field	
Example thermal imaging of			1 mm		Example of SKPFM on a silicon pn	Ag Epoxy	Emitter		

High resolution imaging to

examine defects and identify

materials.

a solar cell stack



Shunting seen in localized regions.Film delamination seen in phase image.



Mechanically remove the encapsulation to expose the semiconductor device.

Examples of thermal imaging of bypass diodes



Rotated views of a failed diode

> Thermal lock-in image (color) overlaid on diode image.





Examine devices through the encapsulation materials.

SEM Energy-Dispersive X-ray Spectroscopy (EDS)





junction region.

Transmission Electron Microscope (TEM)

High resolution analysis of ultra-thin samples. Electron Energy Loss Spectroscopy (EELS) and EDS for compositional analysis.



1 μm TEM example of a dislocation in a silicon solar cell

Time-of-Flight Secondary Ion Mass Spectrometry (TOF-SIMS)

TOF-SIMS shows elemental analysis with spatial resolution in 3D using depth profile sputtering. TOF-SIMS example of sodium profiling in a degraded silicon solar cell







